

$$1) f(E) = \frac{1}{1 + e^{(E-E_f)/kT}} \quad k = 8.62 \cdot 10^{-5} \text{ eV/K} = 1.38 \cdot 10^{-23} \text{ J/K}$$

$$a) E = E_f + kT \rightarrow f(E) = \frac{1}{1 + e^{(kT)/kT}} = \frac{1}{1 + e^1} = \boxed{0.26894}$$

Unoccupied probability
0.73106

$$b) E = E_f + 4kT \rightarrow f(E) = \frac{1}{1 + e^4} = \boxed{0.07986} \quad \times -1$$

1-0.26894

$$c) E = E_f + 9kT \rightarrow f(E) = \frac{1}{1 + e^9} = \boxed{1.2339 \cdot 10^{-4}} \quad \checkmark$$

e^9 = 8103.08

$$2) T = 300 \text{ K} \quad n_0 = 7 \cdot 10^{15} \text{ cm}^{-3}$$

$$a) n_0 = N_c e^{-(E_c - E_f)/kT} \rightarrow E_c - E_f = kT \ln\left(\frac{N_c}{n_0}\right)$$

$$E_c - E_f = (8.617 \cdot 10^{-5})(300) \ln\left(\frac{2.8 \cdot 10^{19}}{7 \cdot 10^{15}}\right) = \boxed{0.2144 \text{ eV}} \quad \checkmark$$

$$b) E_f - E_v = E_c - E_v - (E_c - E_f) \quad \text{and} \quad E_g = E_c - E_v$$

$$E_f - E_v = E_g - (E_c - E_f) = 1.12 - 0.2144 = \boxed{0.906 \text{ eV}} \quad \checkmark$$

$$c) n_0 p_0 = n_i^2 \rightarrow p_0 = \frac{n_i^2}{n_0} = \frac{(1.5 \cdot 10^{10})^2}{7 \cdot 10^{15}} = \boxed{3.2142 \cdot 10^4 \text{ cm}^{-3}} \quad \checkmark$$

$$d) \text{ Since } p_0 < n_0, \text{ the minority carriers are } \boxed{\text{holes}} \quad \checkmark$$

$$e) n_0 = n_i e^{(E_c - E_f)/kT} \quad n_0 p_0 = n_i^2 \rightarrow E_f - E_i = kT \ln\left(\frac{n_0}{n_i}\right)$$

$$E_f - E_i = (8.617 \cdot 10^{-5})(300) \ln\left(\frac{7 \cdot 10^{15}}{1.5 \cdot 10^{10}}\right) = \boxed{0.3374 \text{ eV}} \quad \checkmark$$

3) $n_0 p_0 = n_i^2$ $n_0 = N_d + \frac{n_i^2}{N_a}$

a) $T = 300\text{K}$ $N_d = 10^{15}\text{cm}^{-3}$ $N_a = 4 \times 10^{15}\text{cm}^{-3}$

$n_0 = 10^{15} + \frac{(1.5 \times 10^{10})^2}{4 \times 10^{15}} = \boxed{1.00625 \times 10^{15}\text{cm}^{-3}}$ electron concentration -1

$p_0 = \frac{n_i^2}{n_0} = \frac{(1.5 \times 10^{10})^2}{1.00625 \times 10^{15}} = \boxed{2.236 \times 10^5\text{cm}^{-3}}$ hole concentration -1

b) $T = 300\text{K}$ $N_d = 3 \times 10^{16}\text{cm}^{-3}$ $N_a = 0\text{cm}^{-3}$

$n_0 = \boxed{3 \times 10^{16}\text{cm}^{-3}}$ electron concentration

$p_0 = \frac{(1.5 \times 10^{10})^2}{3 \times 10^{16}} = \boxed{7500\text{cm}^{-3}}$ hole concentration

c) $T = 300\text{K}$ $N_d = N_a = 2 \times 10^{15}\text{cm}^{-3}$

$n_0 = N_d - N_a = \boxed{0\text{cm}^{-3}}$ X -2

$p_0 = \boxed{0\text{cm}^{-3}}$ X

No conduction carriers

d) $T = 375\text{K}$ $N_d = 0\text{cm}^{-3}$ $N_a = 4 \times 10^{15}\text{cm}^{-3}$

$n_0 = \frac{n_i^2}{N_a} = \frac{(1.5 \times 10^{10})^2}{4 \times 10^{15}} = \boxed{5.625 \times 10^4\text{cm}^{-3}}$ electron concentration X -1

$p_0 = \frac{n_i^2}{n_0} = \frac{(1.5 \times 10^{10})^2}{5.625 \times 10^4} = \boxed{4 \times 10^{15}\text{cm}^{-3}}$ hole concentration ✓

e) $T = 450\text{K}$ $N_d = 10^{14}\text{cm}^{-3}$ $N_a = 0$

$n_0 = \boxed{10^{14}\text{cm}^{-3}}$ electron concentration ✓

$p_0 = \frac{(2.5 \times 10^9)^2}{10^{14}} = \boxed{6.25 \times 10^{12}\text{cm}^{-3}}$ hole concentration

X -1

4) $E_g = 1.1 \text{ eV}$ $n_i = 1.5 \times 10^0 \text{ cm}^{-3}$ $E_c - E_F = 0.20 \text{ eV}$

a) $n_0 = N_c e^{-(E_c - E_F)/kT} = 2.8 \times 10^{19} \cdot e^{-(0.2)/(8.617 \times 10^{-5} \times 300)} = 1.2222 \times 10^{16} \text{ cm}^{-3}$
 $N_c = 2.8 \times 10^{19}$

$N_d \approx n_0 = 1.2222 \times 10^{16} \text{ cm}^{-3}$ ✓

b) $N_a = 10^{16} \text{ cm}^{-3}$

$n_0 = N_d - N_a \rightarrow N_d = n_0 + N_a = 1.2222 \times 10^{16} + 10^{16} = 2.2222 \times 10^{16}$

$\Delta N_d = N_d - N_a = 2.2222 \times 10^{16} - 10^{16} = 1.2222 \times 10^{16} \text{ cm}^{-3}$ X -2

5) The effective mass of electrons in the T-valley of GaAs is smaller and results in higher mobility. ✓

If electrons are promoted from T to L valley, their effective mass increases, mobility decreases, and conductivity decreases. ✓

6) $L = 2 \text{ cm}$ $A = 0.1 \text{ cm}^2$ $N_d = 10^{15} \text{ cm}^{-3}$ $R = 90 \Omega$ $v_{sat} = 10^7 \text{ cm/s}$ $E_{sat} = 10^5 \text{ V/cm}$

$v_d = \mu_n E$ $E = \frac{V}{L}$ $\mu_n = 1350 \text{ cm}^2/\text{Vs}$ $I = \frac{V}{R}$

a) $V = 100 \text{ V}$ $E = \frac{V}{L} = \frac{100}{2} = 50 \text{ V/cm}$ $v_d = 1350 \cdot 50 = 67500 \text{ cm/s}$

$I = \frac{V}{R} = \frac{100}{90} = 1.11 \text{ A}$ ✓

b) $V = 200 \text{ V}$ $E = \frac{V}{L} = \frac{200}{2} = 100 \text{ V/cm}$ $v_d = 1350 \cdot 100 = 135000 \text{ cm/s}$

$I = \frac{V}{R} = \frac{200}{90} = 2.22 \text{ A}$ ✓

c) $V = 10^6 \text{ V}$ $E = \frac{V}{L} = \frac{10^6}{2} = 5 \times 10^5 \text{ V/cm}$ ← above saturation field (10^5 V/cm) $v_d = v_{sat} = 10^7 \text{ cm/s}$

$I = \frac{V}{R} = \frac{10^6}{90} = 1.11 \times 10^4 \text{ A}$ X -1

$I = A q n v_{sat}$ -2

Current is linearly proportional to Voltage until the drift velocity reaches saturation ✓